

SINGLE LOW VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIER

Description

The AZV321 is single low voltage (2.7V to 5.5V) operational amplifier which has rail-to-rail output swing capability. The input common-mode voltage range includes ground. The chip exhibits excellent speed-power ratio, achieving 1MHz of bandwidth and 1V/ μ s of slew rate with low supply current.

The AZV321 is built with BiCMOS process. It has bipolar input and output stages for improved noise performance, low input offset and higher output current drive.

The AZV321 is available in the package of SC-70-5, which is approximately half the size of SOT-23-5. The small package saves space on pc boards, and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The AZV321 is also available in standard SOT-23-5 package.

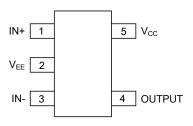
Features (For V_{CC} =5V and V_{EE} =0V, Typical unless Otherwise Noted)

- Guaranteed 2.7V to 5.5V Performance
- No Crossover Distortion
- Gain-Bandwidth Product 1MHz
- Industrial Temperature Range: -40°C to +85°C
- Low Supply Current: 130μA
- Rail-to-Rail Output Swing under $10k\Omega$ Load:

 V_{OH} up to V_{CC} -10mV V_{OL} near to V_{EE} +65mV V_{CM} : -0.1V to V_{CC} -0.8V

Pin Assignments

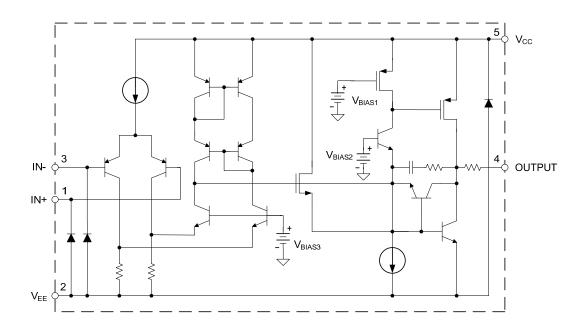
KS/K Package (SC-70-5/SOT-23-5)



Applications

- Active Filters
- Low Power, Low Voltage Applications
- General Purpose Portable Devices
- Cellular Phone, Cordless Phone
- Battery-Powered Systems

Functional Block Diagram







AZV321

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Rating	Unit
V _{CC}	Power Supply Voltage	6	٧
TJ	Operation Junction Temperature	150	°C
T _{STG}	Storage Temperature Range	age Temperature Range -65 to 150	
T _{LEAD}	Lead Temperature (Soldering, 10 Seconds)	260	°C
	ESD (Machine Model)	200	V
	ESD (Human Body Model)	2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol Parameter		Min	Max	Unit
V _{CC}	Supply Voltage	2.7	5.5	V
T _A	Ambient Operating Temperature Range	-40	85	°C





AZV321

Electrical Characteristics

AZV321-2.7V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =2.7V, V_{EE} =0V, V_{CM} =1.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
\/	Input Offset Voltage			1.7	7	m\/
V _{IO}	Input Offset Voltage				9	mV
1	January Dina Comment			11	250	nA
l _Β	Input Bias Current				500	
1	Input Offset Current			5	50	η.Λ
I _{IO}	nput Offset Current —				150	nA
V _{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		1.9	V
ı	Cumply Current	\\ -\\ /2 \\ -1 no lood		80	170	
I _{CC}	Supply Current	V _O =V _{CC} /2, A _{VCL} =1, no load			270	μA
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤1.7V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V	50	60		dB
I _{SOURCE}	Outside Object Circuit Comment	V _O =0V	5	20		mA
I _{SINK}	Output Short Circuit Current	V _O =2.7V	10	30		mA
V _{OH}	Outrot Valta na Outra	D 401-0 t- 4.051/	2.60	2.69		V
V _{OL}	Output Voltage Swing	R_L =10kΩ to 1.35V		60	180	mV
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
фм	Phase Margin			60		Deg
G _M	Gain Margin			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.



Electrical Characteristics (Cont.)

AZV321-5V Electrical Characteristics (All limits are guaranteed for T_A =25°C, V_{CC} =5V, V_{EE} =0V, V_{CM} =2.0V, V_O = V_{CC} /2 and R_L >1M Ω , limits in **bold types** are guaranteed for T_A =-40°C to 85°C, unless otherwise specified. Note 2)

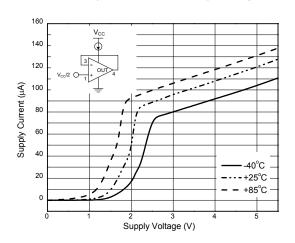
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
1/	Innut Official Voltage			1.7	7	mV
V_{IO}	Input Offset Voltage				9	
1				11	250	η.Λ
l _Β	Input Bias Current				500	nA
I _{IO}	Input Offset Current			5	50	nA
·IO	·				150	11/ \
V_{CM}	Input Common Mode Voltage Range	for CMRR≥50dB	-0.1		4.2	V
laa	Supply Current	V _O =V _{CC} /2, A _{VCL} =1, no load		130	250	^
Icc	Supply Current	V0-VCC/2, AVCL-1, 110 10au			350	μA
Gv	Large Signal Voltage Cain	R _L =2kΩ	1.7 11 5 -0.1 84 100 80 50 65 50 60 10 160 4.7 4.96 4.6 4.9 4.99 4.8 120 65 1 1 1 60	100		- dB
9	Large Signal Voltage Gain	KL-2K11				
CMRR	Common Mode Rejection Ratio	0≤V _{CM} ≤4V	50	65		dB
PSRR	Power Supply Rejection Ratio	2.7V≤V _{CC} ≤5V, V _O =1V, V _{CM} =1V	50	60		dB
Isource	Output Short Circuit Current	V _O =0V	5	60		mA
I _{SINK}	Output Short Circuit Current	V _O =5V	10	160		mA
		R_L =2k Ω to 2.5V	4.7	4.96		- V
V_OH			4.6			
V OH		R_L =10k Ω to 2.5V	4.9	4.99		
	Output Voltage Swing	11[-10K22 to 2.57	4.8			
	Cutput Voltage Owing	R_i =2k Ω to 2.5V		120	300	
V_{OL}		11_2132 to 2.50			400	mV
V OL		R_L =10k Ω to 2.5V		65	180	
		14_ 10/32 to 2.0 V			280	
SR	Slew Rate			1		V/µS
GBWP	Gain Bandwidth Product	C _L =200pF		1		MHz
фм	Phase Margin			60		Deg
G_M	Gain Margin			10		dB

Note 2: Limits over the full temperature are guaranteed by design, but not tested in production.

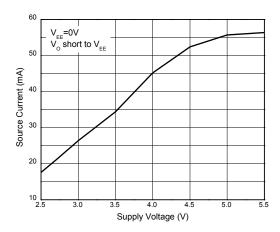


Performance Characteristics

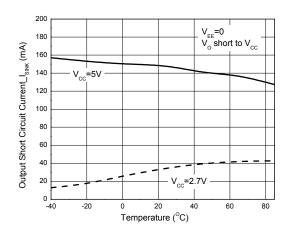
Supply Current vs. Supply Voltage



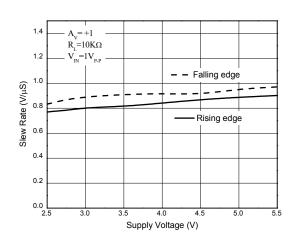
Output Source Current vs. Supply Voltage



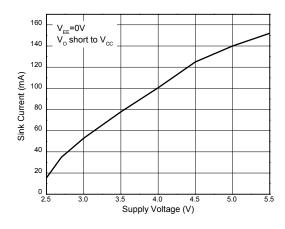
Short Circuit Current $_{I_{SINK}}$ vs. Temperature



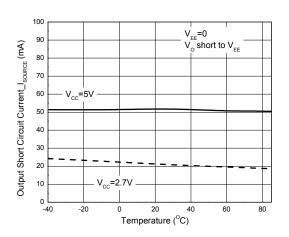
Slew Rate vs. Supply Voltage



Output Sink Current vs. Supply Voltage



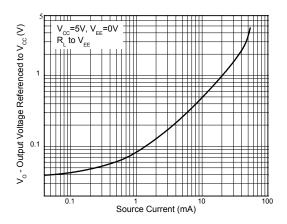
Short Circuit Current_ I_{SOURCE} vs. Temperature



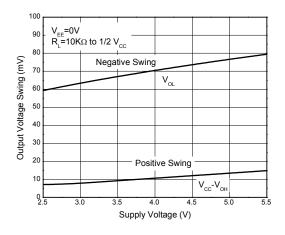


Performance Characteristics (Cont.)

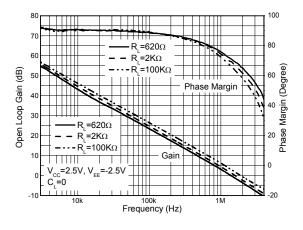
Output Voltage vs. Source Current



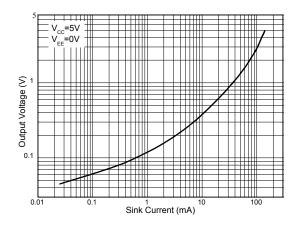
Output Voltage Swing vs. Supply Voltage



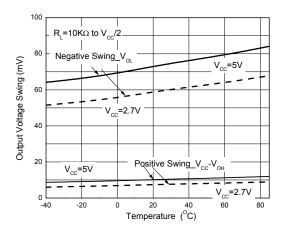
Gain and Phase vs. Frequency and Resistive Load



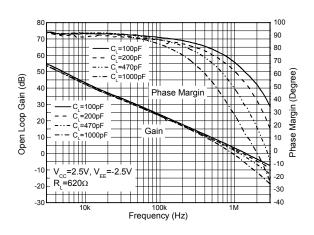
Output Voltage vs. Sink Current



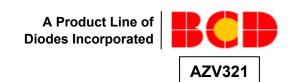
Output Voltage Swing vs. Temperature



Gain and Phase vs.
Frequency and Capacitive Load

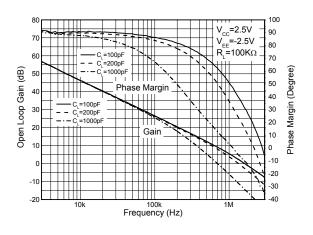




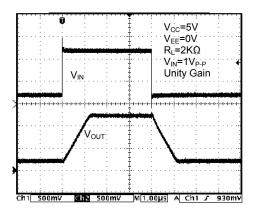


Performance Characteristics (Cont.)

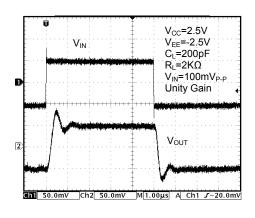
Gain and Phase vs. Frequency and Capacitive Load



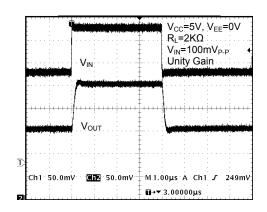
Non-Inverting Input Large Signal Pulse Response



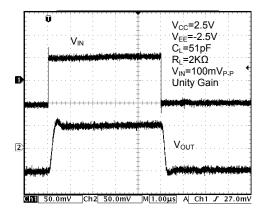
Output with Excessive Capacitive Load



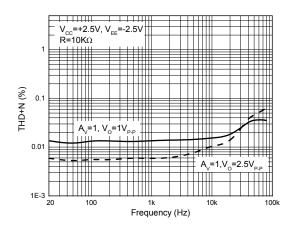
Non-Inverting Input Small Signal Pulse Response



Output with Excessive Capacitive Load

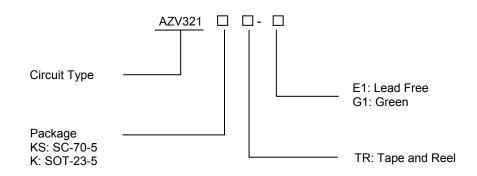


THD+N vs. Frequency





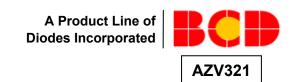
Ordering Information



Doolsono	Temperature	Part N	umber	Marki	ing ID	Dooking Tune
Package	Range	Lead Free	Green	Lead Free	Green	Packing Type
SC-70-5	-40 to 85°C	AZV321KSTR-E1	AZV321KSTR-G1	21	B1	Tape & Reel
SOT-23-5		AZV321KTR-E1	AZV321KTR-G1	E6D	G6D	Tape & Reel

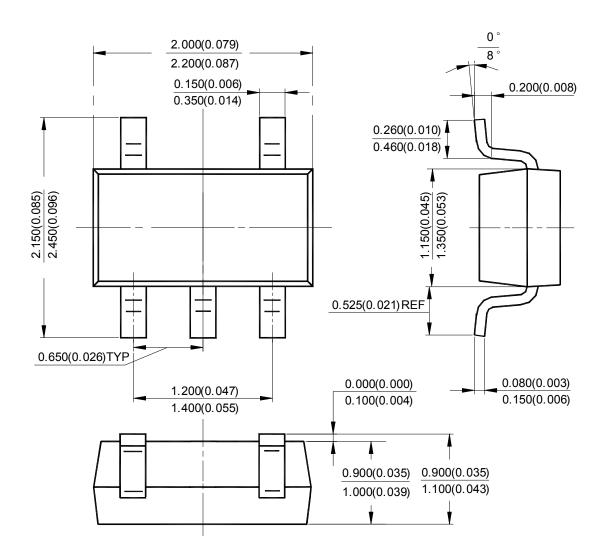
BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.





Package Outline Dimensions (All dimensions in mm(inch).)

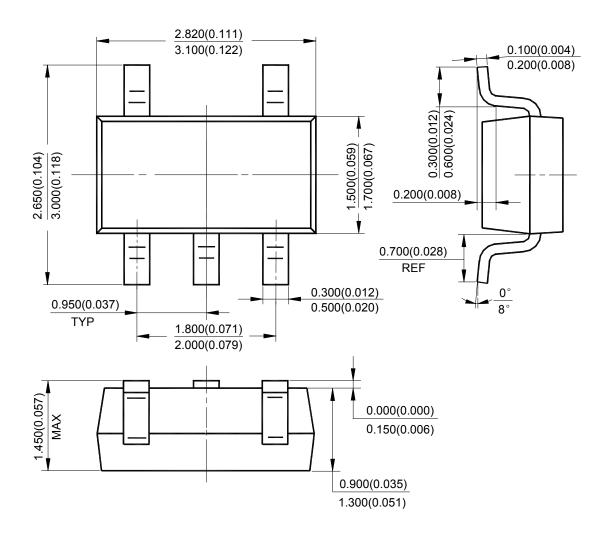
SC-70-5





Package Outline Dimensions (Cont. All dimensions in mm(inch).)

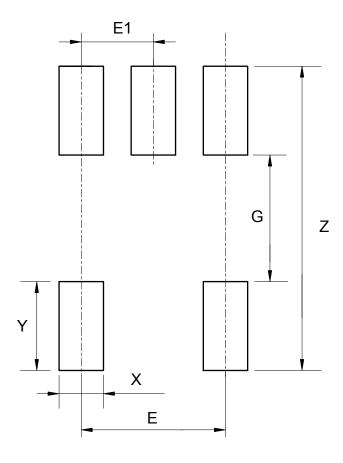
SOT-23-5





Suggested Pad Layout

SC-70-5

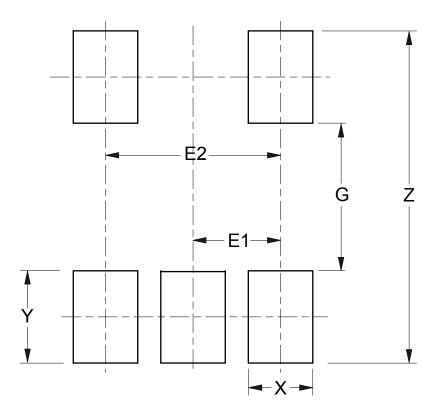


Dimensions	Z	G	X	Y	Е	E1
Dimensions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	2.740/0.108	1.140/0.045	0.400/0.016	0.800/0.031	1.300/0.051	0.650/0.026



Suggested Pad Layout (Cont.)

SOT-23-5



Dimensions	Z	G	X	Y	E1	E2
Difficusions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



AZV321

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